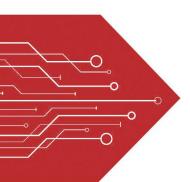
## MSKSEMI















**ESD** 

TVS

TSS

MOV

**GDT** 

**PLED** 

# Product data sheet

#### **FEATURES**

- Low forward voltage
- · High current capability
- · High forward surgecapability
- Low power losses, High efficiency
- Guarding for over voltage protection

#### **APPLICATIONS**

Low VF Schottky barrier rectifier are designed for high freqency, miniature switched mode power supplies such as adapters, lighting and on-board DC/DC conerters

#### **MECHANICAL DATA**

Case: Molded plasticPolarity: As markedMounting Position: Any

• Molded Plastic: ULFlammability Classification Rating 94V-0 • Lead free in compliance with EURoHS 2011/65/EU directive

• Solder bath temperature 275°C maximum,10s per JESD 22-B106

Primary Characteristic		
lo	2*10A	
$V_{RRM}$	45V	
I <sub>FSM</sub>	260A	
V <sub>F</sub>	0.49V	
T₃max	150℃	
Assembly code	AA	

:Ta=25°C uı	nless otherwis	e specified	
	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage		45	V
	V <sub>RWM</sub>	45	V
	V <sub>DC</sub>	45	V
Per Leg		10	Δ.
Total	lo lo	20	— A
f Sine-wave	I <sub>FSM</sub>	260	A
	TJ	150	°C
	T <sub>STG</sub>	-40 to +150	°C
TO-220AB,TO-263,TO-252		2	°C/W
TO-220F		4	
	Per Leg Total f Sine-wave	Symbol   V <sub>RRM</sub>   V <sub>RWM</sub>   V <sub>DC</sub>   Per Leg   Io   I   Total   I   FSM   TJ   TJ   TJ   Total   TJ   TJ   TJ   Total   TJ   TJ   TJ   TJ   TJ   TJ   TJ   T	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

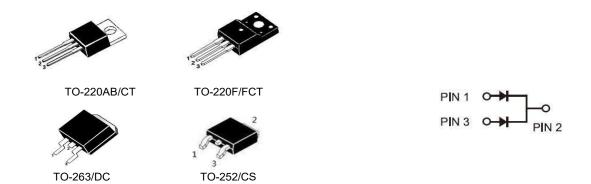
Note1: Thermal resistance from Junction to case per leg mounted on heatsink.

Electrical Characteristics (Per	Leg) unless	otherwise	specified		
Characteristics		Symbol	Va	lue	Unit
Forward Voltage Drop(Note2)			Тур.	Max.	
-11 -21	TA=25°C	] [	0.42	-	
at I <sub>F</sub> =3A	TA=125°C	] [	0.34	-	
-+1 -5A	TA=25°C	V <sub>F</sub>	0.46	-	V
at I <sub>F</sub> =5A	TA=125°C	] [	0.41	-	
-11 -400	TA=25°C	] [	0.56	0.60	
at I <sub>F</sub> =10A	TA=125°C	] [	0.49	-	
Maximum Reverse Current at V <sub>R</sub> =45V	TA=25°C		40	100	μΑ
	TA=125°C	I <sub>R</sub>	12	-	mA

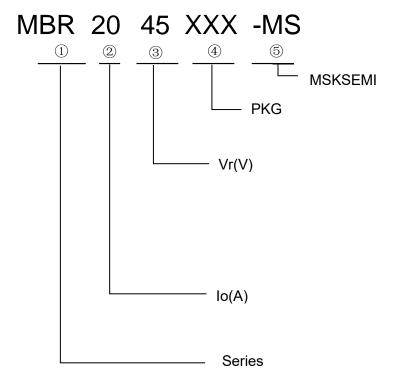
Note2:Pulse test: 300 µs pulse width, 1 % duty cycle



#### SCHOTTKY BARRIER RECTIFIER



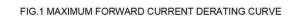
#### P/N Information

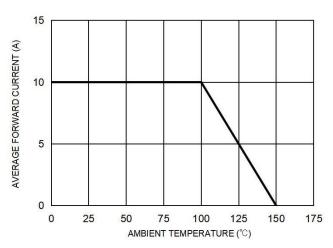


1)	2	3	4	(5)
系列	平均整流电流	直流反向耐压	封装	MSKSEMI

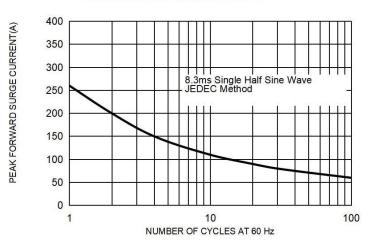


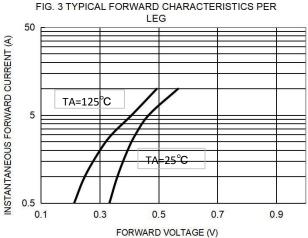
#### RATINGS AND CHARACTERISTIC CURVES

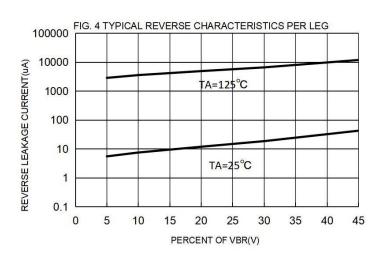




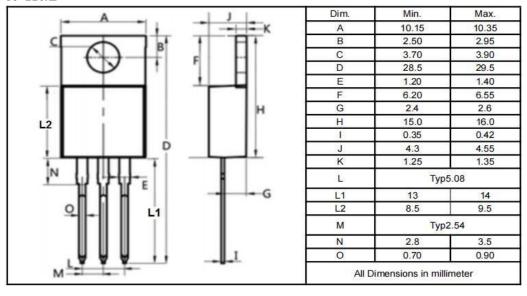
## FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG





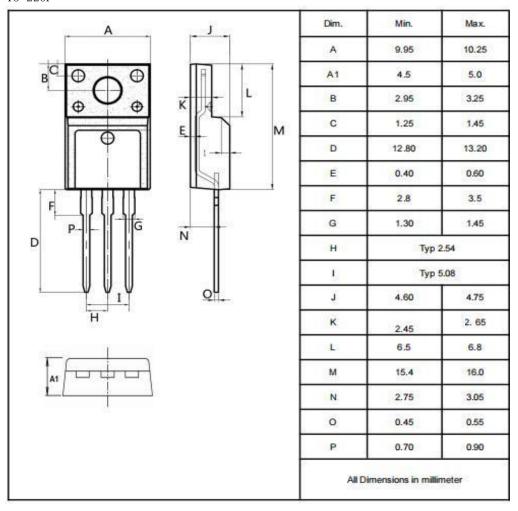


TO-220AB



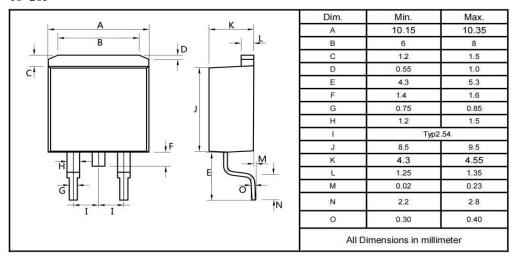
P/N	PKG	QTY
MBR2045CT-MS	TO-220AB	50pcs/tube 1000pcs/box

TO-220F



P/N	PKG	QTY
MBR2045FCT-MS	TO-220F	50pcs/tube 1000pcs/box

TO-263

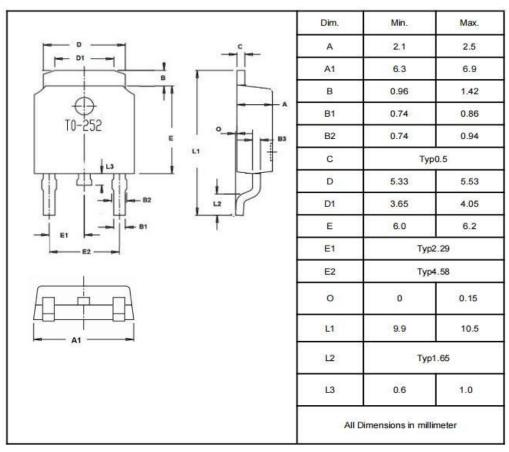


#### **REEL SPECIFICATION**

P/N	PKG	QTY
MBR2045DC-MS	TO-263	50pcs/tube 1000pcs/box

P/N	PKG	QTY
MBR2045DC-R-MS	TO-263	800pcs

TO-252



P/N	PKG	QTY
MBR2045CS-MS	TO-252	2500



Semiconductor Compiance

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